Structure–property trends in π -stacked dithiazolo-dithiazolyl conductors

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The resonance stabilized dithiazolo-dithiazolyl radical 1b adopts a slipped π -stack structure exhibiting weak 1-D ferromagnetic coupling; variable temperature conductivity measurements indicate $\sigma_{\rm RT} = 2 \times 10^{-6} \, {\rm S \, cm^{-1}}$.

In an ideal neutral radical conductor a stack of π -radicals should function like an array of atoms in an elemental metal; the bulk material would possess a half-filled energy band, as in elemental sodium, and possess a metallic ground state.¹ In practice, however, radicals tend to dimerize (a Peierls instability)² and, more importantly, if association can be suppressed, the high on-site Coulomb repulsion $U (\approx IP - EA)$ associated with most stable radicals leads to a Mott insulating state.³ The design of radicals with good ion energetics, i.e., low disproportionation enthalpies ($\Delta H_{\text{disp}} = \text{IP} - \text{EA}$) is therefore crucial to the development of materials with enhanced conductivities.⁴ In this regard the resonance stabilized 1,2,3-dithiazolo-1,2,3-dithiazolyl framework 1, with calculated $\Delta H_{\rm disp}$ = 4.7 eV, represents an appealing building block.⁵ In the solid state, however, the recently reported compound 1a (R = Cl) is a Mott insulator, as a result of slippage of the radical π -stacks and consequent loss of bandwidth $\hat{W}^{.5}$ In an effort to modify the crystal structure, and improve tranpsort properties, we have pursued the prototypal radical **1b** ($\hat{\mathbf{R}} = \hat{\mathbf{H}}$), in the belief that stack slippage might be reduced, and W increased.



The reported preparative route to 1a involves N-methylation of the zwitterionic heterocycle 2 (R = Cl)⁶ with MeOTf followed by reduction of the resulting cation $[1]^+$ with Cp*₂Fe.⁵ We have now developed a much simpler route which provides easy access to both 1a and 1b.⁺ Both syntheses involve, as a first step, N-methylation of 2,6-diaminopyridine with MeOTf to give $3.^{7}$ This reaction affords a mixture of protonated and methylated salts,⁸ from which the former can be removed by washing the crude product with NEt₃ in C₂H₄Cl₂. Subsequent treatment of **3** (3.02 g, 11.0 mmol) with excess S_2Cl_2 (17.8 g) at reflux in MeCN for 16 h affords a deep blue solution which, upon cooling, yields lustrous red plates of [1a][OTf] (4.38 g, 10.2 mmol, 93%). If **3** (5.1 g, 18.9 mmol) and S₂Cl₂ (13.5 g) are brought together in CH₃CN at room temperature in the presence of NEt₃ (11.6 g, 0.114 mmol) as an auxiliary base, and the mixture left to react for 5 days, a blue-black insoluble precipitate of [1b][Cl] is formed. Purification⁵ and metathesis of the latter with AgSbF₆ in CH₃CN generates a deep blue solution which, upon solvent removal and recrystallization from HOAc, affords deep red crystals of [1b][SbF₆]. Subsequent reduction of $[1b][SbF_6]$ (0.943 g, 1.94 mmol) with Cp*₂Fe (0.634 g, 1.94 mmol) in degassed CH₃CN affords **1b**, (0.425 g, 1.94 mmol) 1.72 mmol, 89%), which may be recrystallized from degassed toluene as black needles.



The EPR spectrum of **1b** in CH₂Cl₂ (Fig. 1) is consistent with the expected spin distribution, and can be simulated in terms of strong coupling from the two wing nitrogens, with weaker coupling to the central N, the unique proton and the N-methyl protons. Cyclic voltammetry on solutions of [**1b**][SbF₆] in MeCN (Pt electrodes, Buⁿ₄NPF₆ supporting electrolyte) reveals a reversible reduction wave (**1b**^{+/0}) with $E_{1/2} = -0.130$ V (*vs.* SCE) and an irreversible reduction (**1b**^{0/-1}) with $E_{pc} = -0.952$ V (*vs.* SCE). As expected from the replacement of Cl by H, both these processes occur at slightly more cathodic potentials than those in **1a**.⁵ The peak-to-peak separation $E_{pc}(\mathbf{1}^{+/0}) - E_{pc}(\mathbf{1}^{0/-1})$ = 0.789 V in **1b** is smaller than **1a** (0.830 V). These data all militate in terms of a low on-site Coulomb repulsion *U*.⁹



Fig. 1 EPR spectrum (293 K, CH₂Cl₂, SW = 3 mT, g = 2.0082) of radical **1b**. Hyperfine coupling constants are $a_N = 0.317$ (2N) and 0.0620 (1N), $a_H = 0.230$ (1H) and 0.034 (3H) mT.

The crystal structure of radical **1b**[‡] belongs to the orthorhombic space group $P2_12_12_1$, as does that of **1a**.⁵ The cell packing (Fig. 2), with radical π -stacks hinged around 2_1 axes, is similar to that of **1a**. At 293 K the unit cell dimensions *b* (15.194(5) Å in **1a**, 11.962(3) Å in **1b**) and *c* (15.069(4) Å in **1a**, 18.262(5) Å in **1b**) are, however, substantially different. The



Fig. 2 Unit cell of 1b.

cell repeat distances a also differ (4.2464(12) Å in 1a,3.9626(10) Å in **1b**). The latter parameters herald a change in the degree of slippage in the π -stacks. As illustrated in Fig. 3, the slippage angle τ (the angle between the mean molecular plane and the stacking axis) is larger for **1b**, *i.e.*, the radicals are more nearly superimposed, as expected from the replacement of Cl by H. However, the plane-to-plane separation δ is also larger, suggesting that Me...Me repulsions are forcing the molecules apart as they slide on top of one another.§



Fig. 3 Slipped π -stacks in 1a (left) and 1b (right) illustrating the plate slippage angles τ (= 54.81(13)° in **1a** and 62.04(7)° in **1b**) and mean plane separations δ (= 3.470(5) Å in **1a** and 3.500(6) Å in **1b**).

Magnetic susceptibility (χ) measurements on microcrystalline samples of 1b have been performed over the temperature range 320–5 K. Like **1a**, the temperature dependence of χ for **1b** shows a Curie dependence down to near 100 K, with C = 0.345, $\chi_0 = 120.4 \times 10^{-6}$ emu mol⁻¹. Consistently, the number of Curie spins (Fig. 4) remains constant near 0.92 down to 125 K, and then starts to rise. There is slight discontinuity at 85 K, which may signal a subtle phase change similar to that observed for 1a, after which the free spin count increases more sharply, reaching a value of 7.2 at 5 K. This enhancement is



Fig. 4 Number of Curie spins vs T for 1b.



Fig. 5 Single crystal conductivity of 1b as a function of 1/T.

characteristic of weak ferromagnetic coupling along the π stacks.5,10

Single crystal conductivity (σ) measurements along the needle axis of 1b over the temperature range 320-150 K indicate (Fig. 5) that the conductivity is activated, with a value of $\sigma = 2 \times 10^{-6}$ S cm⁻¹ at 300 K, *i.e.*, very close to that found for 1a.⁵ The derived activation energy Δ (one-half of the band gap for an intrinsic semiconductor) is 0.41 eV (0.42 eV for 1a).

We attribute the similarity in the magnetic and conductivity behaviour of 1a and 1b to the combined effects of decreases in both τ and δ . Because the changes offset one another, there is very little difference in (EHT calculated) intrastack overlap, and hence bandwidth W, between the two compounds.⁵

Notes and references

[†] Satisfactory chemical analyses were obtained for **1b** and **[1b]**[SbF₆]. The IUPAC name for 1b is 4-methyl-4H-bis[1,2,3]dithiazolo[4,5-b:5',4'-e]pyridin-2-yl.

‡ Crystal data for 1b: data were collected at 293 K on a Rigaku Mercury CCD diffractometer with graphite monochromated Mo K α radiation (λ = 0.7107 Å) using ω scans. The structure was solved and refined by full matrix least-squares analysis which minimized $\Sigma w(\Delta F)^2$. C₆H₄N₃S₄, M = 246.36, orthorhombic, space group $P2_12_12_1$, with a = 3.9626(10), b = 11.962(3), c = 18.262(5) Å, V = 865.6(4) Å³, Z = 4, $D_c = 1.890$ g cm⁻³, $\mu = 1.044$ mm-1. 134 parameters were refined using 977 (all) unique reflections to give R = 0.0338 and $R_w = 0.0597$. CCDC 191497. See http://www.rsc.org/ suppdata/cc/b2/b207735n/ for crystallographic data in CIF or other electronic format.

§ Mean intramolecular distances (ranges in parentheses) for 1b: S-S, 2.097(10); S–N, 1.660(1); N–C, 1.311(6); S–C, 1.727(2) Å.

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